



PATENT
Attorney Docket No.: 021653-000900US
Client Ref. No.: I-02-049

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Herb H. Huang et al.

Application No.: 10/773,522

Filed: February 6, 2004

For: SEMICONDUCTOR MEMORY
CELL WITH BURIED DOPANT BIT
LINES AND SALICIDED
POLYSILICON WORD LINES
ISOLATED BY AN ARRAY OF
BLOCKS

Customer No.: 20350

Confirmation No. 6545

Examiner: N. Drew Richards

Technology Center/Art Unit: 2815

AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In response to the Office Action mailed April 6, 2005, please enter the following amendments and remarks:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 6 of this paper.

Amendments to the Drawings begin on page 8 of this paper and include both attached replacement sheets and annotated sheet showing changes.

Remarks/Arguments begin on page 9 of this paper.